

DM74S30 8-Input NAND Gate

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FAIRCHILD

SEMICONDUCTOR

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Absolute Maximum Ratings(Note 1)

| Supply Voltage | 7V |
|--------------------------------------|-----------------------------------|
| Input Voltage | 5.5V |
| Operating Free Air Temperature Range | $0^{\circ}C$ to $+70^{\circ}C$ |
| Storage Temperature Range | $-65^{\circ}C$ to $+150^{\circ}C$ |

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

| Symbol | Parameter | Min | Nom | Max | Units |
|-----------------|--------------------------------|------|-----|------|-------|
| V _{CC} | Supply Voltage | 4.75 | 5 | 5.25 | V |
| V _{IH} | HIGH Level Input Voltage | 2 | | | V |
| V _{IL} | LOW Level Input Voltage | | | 0.8 | V |
| он | HIGH Level Output Current | | | -1 | mA |
| OL | LOW Level Output Current | | | 20 | mA |
| T _A | Free Air Operating Temperature | 0 | | 70 | °C |

Electrical Characteristics

over recommended operating free air temperature (unless otherwise noted)

| Symbol | Parameter | Conditions | Min | Typ (Note 2) | Max | Units |
|------------------|-----------------------------------|--|-----|-----------------|------|-------|
| VI | Input Clamp Voltage | $V_{CC} = Min, I_I = -18 \text{ mA}$ | | | -1.2 | V |
| V _{OH} | HIGH Level Output Voltage | $V_{CC} = Min, I_{OH} = Max$ $V_{IL} = Max$ | 2.7 | 3.4 | | V |
| V _{OL} | LOW Level Output Voltage | $V_{CC} = Min, I_{OL} = Max$ $V_{IH} = Min$ | | | 0.5 | V |
| l _l | Input Current @ Max Input Voltage | $V_{CC} = Max, V_I = 5.5V$ | | | 1 | mA |
| I _{IH} | HIGH Level Input Current | $V_{CC} = Max, V_I = 2.7V$ | | | 50 | μA |
| I _{IL} | LOW Level Input Current | $V_{CC} = Max, V_I = 0.5V$ | | | -2 | mA |
| los | Short Circuit Output Current | V _{CC} = Max (Note 3) | -40 | | -100 | mA |
| I _{CCH} | Supply Current with Outputs HIGH | V _{CC} = Max | | 3 | 5 | mA |
| I _{CCL} | Supply Current with Outputs LOW | V _{CC} = Max | | 5.5 | 10 | mA |

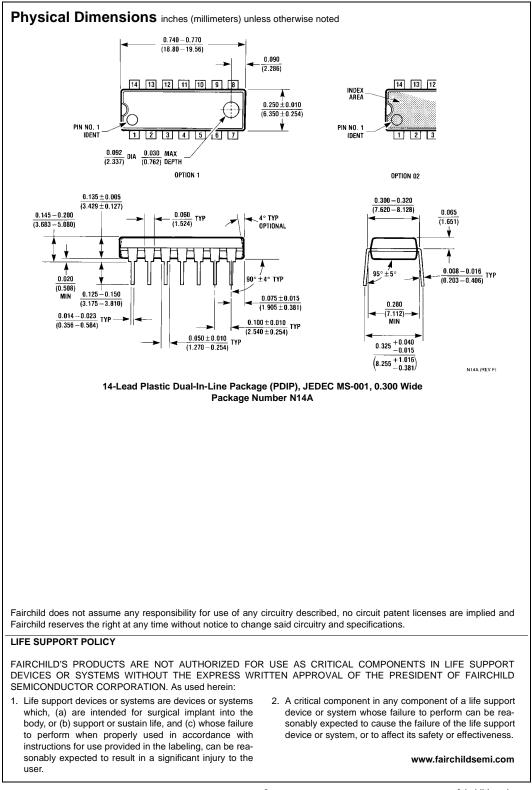
Note 2: All typicals are at V_{CC} = 5V, $T_A = 25^{\circ}C$.

Note 3: Not more than one output should be shorted at a time, and the duration should not exceed one second.

Switching Characteristics

at $V_{CC} = 5V$ and $T_A = 25^\circ C$

| - | Parameter | R _L = 280Ω | | | | |
|------------------|--------------------------|------------------------|-----|-----------------------|-----|-------|
| Symbol | | C _L = 15 pF | | $C_L = 50 \text{ pF}$ | | Units |
| | | Min | Max | Min | Max | |
| t _{PLH} | Propagation Delay Time | 2 | 6 | 2 | 8 | ns |
| | LOW-to-HIGH Level Output | 2 | 0 | 2 | 0 | 113 |
| t _{PHL} | Propagation Delay Time | 2 | 7 | 3 | 10 | 20 |
| | HIGH-to-LOW Level Output | 2 | 1 | 3 | 10 | ns |



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